

Advance Information

Enhanced Mixed Frequency Mode GreenLine™ PWM Controller:

Fixed Frequency, Variable Frequency, Standby Mode

The MC44603A is an enhanced high performance controller that is specifically designed for off–line and dc–to–dc converter applications. This device has the unique ability of automatically changing operating modes if the converter output is overloaded, unloaded, or shorted, offering the designer additional protection for increased system reliability. The MC44603A has several distinguishing features when compared to conventional SMPS controllers. These features consist of a foldback facility for overload protection, a standby mode when the converter output is slightly loaded, a demagnetization detection for reduced switching stresses on transistor and diodes, and a high current totem pole output ideally suited for driving a power MOSFET. It can also be used for driving a bipolar transistor in low power converters (< 150 W). It is optimized to operate in discontinuous mode but can also operate in continuous mode. Its advanced design allows use in current mode or voltage mode control applications.

Current or Voltage Mode Controller

- Operation up to 250 kHz Output Switching Frequency
- Inherent Feed Forward Compensation
- Latching PWM for Cycle-by-Cycle Current Limiting
- Oscillator with Precise Frequency Control

High Flexibility

- Externally Programmable Reference Current
- Secondary or Primary Sensing
- Synchronization Facility
- High Current Totem Pole Output
- Undervoltage Lockout with Hysteresis

Safety/Protection Features

- Overvoltage Protection Against Open Current and Open Voltage Loop
- Protection Against Short Circuit on Oscillator Pin
- Fully Programmable Foldback
- Soft-Start Feature
- Accurate Maximum Duty Cycle Setting
- Demagnetization (Zero Current Detection) Protection
- Internally Trimmed Reference
- Enhanced Output Drive

GreenLine Controller: Low Power Consumption in Standby Mode

- Low Startup and Operating Current
- Fully Programmable Standby Mode
- Controlled Frequency Reduction in Standby Mode
- Low dV/dT for Low EMI Radiations

GreenLine is a trademark of Motorola, Inc.

MC44603A

MIXED FREQUENCY MODE GREENLINE PWM* CONTROLLER:

VARIABLE FREQUENCY, FIXED FREQUENCY, STANDBY MODE

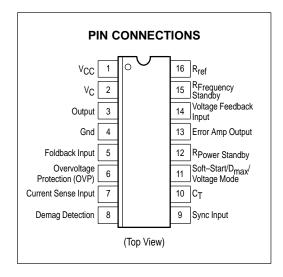
* PWM = Pulse Width Modulation



P SUFFIX PLASTIC PACKAGE CASE 648



DW SUFFIXPLASTIC PACKAGE
CASE 751G
(SOP-16L)



ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC44603AP	T. 250 to 1050C	Plastic DIP-16
MC44603ADW	$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$	SOP-16L

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Total Power Supply and Zener Current	(ICC + IZ)	30	mA
Supply Voltage with Respect to Ground (Pin 4)	V _C V _C C	18	V
Output Current (Note 1) Source Sink	I _O (Source) I _O (Sink)	-750 750	mA
Output Energy (Capacitive Load per Cycle)	W	5.0	μЈ
RF Stby, CT, Soft-Start, Rref, RP Stby Inputs	V _{in}	-0.3 to 5.5	V
Foldback Input, Current Sense Input, E/A Output, Voltage Feedback Input, Overvoltage Protection, Synchronization Input	V _{in}	-0.3 to V _{CC} + 0.3	V
Synchronization Input High State Voltage Low State Reverse Current	VIH VIL	V _{CC} + 0.3 -20	V mA
Demagnetization Detection Input Current Source Sink	Idemag-ib (Source) Idemag-ib (Sink)	-4.0 10	mA
Error Amplifier Output Sink Current	IE/A (Sink)	20	mA
Power Dissipation and Thermal Characteristics P Suffix, Dual–In–Line, Case 648 Maximum Power Dissipation at T _A = 85°C Thermal Resistance, Junction–to–Air DW Suffix, Surface Mount, Case 751G Maximum Power Dissipation at T _A = 85°C Thermal Resistance, Junction–to–Air	PD R _θ JA PD R _θ JA	0.6 100 0.45 145	W °C/W W °C/W
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature	TA	-25 to +85	°C

NOTES: 1. Maximum package power dissipation limits must be observed. 2. ESD data available upon request.

ELECTRICAL CHARACTERISTICS (V_{CC} and V_{C} = 12 V, [Note 3], R_{ref} = 10 k Ω , C_{T} = 820 pF, for typical values T_{A} = 25°C, for min/max values T_{A} = -25° to +85°C [Note 4], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OUTPUT SECTION					
Output Voltage (Note 5)					V
Low State (I _{Sink} = 100 mA)	V _{OL}	-	1.0	1.2	
$(I_{Sink} = 500 \text{ mA})$		-	1.4	2.0	
High State (I _{Source} = 200 mA)	Voн	-	1.5	2.0	
(I _{Source} = 500 mA)		-	2.0	2.7	
Output Voltage During Initialization Phase	VOL				V
$V_{CC} = 0$ to 1.0 V, $I_{Sink} = 10 \mu A$		-	-	1.0	
$V_{CC} = 1.0 \text{ to } 5.0 \text{ V}, I_{Sink} = 100 \mu\text{A}$		-	0.1	1.0	
$V_{CC} = 5.0 \text{ to } 13 \text{ V}, I_{Sink} = 1.0 \text{ mA}$		-	0.1	1.0	
Output Voltage Rising Edge Slew–Rate (C _L = 1.0 nF, T _J = 25°C)	dVo/dT	-	300	-	V/μs
Output Voltage Falling Edge Slew–Rate (C _L = 1.0 nF, T _J = 25°C)	dVo/dT	_	-300	-	V/μs
ERROR AMPLIFIER SECTION					
Voltage Feedback Input (V _{E/A out} = 2.5 V)	V _{FB}	2.42	2.5	2.58	V
Input Bias Current (V _{FB} = 2.5 V)	I _{FB-ib}	-2.0	-0.6	_	μА
Open Loop Voltage Gain (V _{E/A out} = 2.0 to 4.0 V)	AVOL	65	70	_	dB

NOTES: 3. Adjust V_{CC} above the startup threshold before setting to 12 V.
4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
5. V_C must be greater than 5.0 V.

ELECTRICAL CHARACTERISTICS (continued) (V_{CC} and V_{C} = 12 V, [Note 3], R_{ref} = 10 k Ω , C_{T} = 820 pF, for typical values T_{A} = 25°C, for min/max values T_{A} = -25° to +85°C [Note 4], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
ERROR AMPLIFIER SECTION (continued)	·				
Unity Gain Bandwidth	BW				MHz
$T_{J} = 25^{\circ}C$		-	4.0	_ 	
$T_{J} = -25^{\circ} \text{ to } +85^{\circ}\text{C}$.,	-	_	5.5	,,
Voltage Feedback Input Line Regulation (V _{CC} = 10 to 15 V)	VFBline-reg	-10	-	10	mV
Output Current Sink ($VE/A_{Out} = 1.5 V, V_{FB} = 2.7 V$)	lotati	2.0	12	_	mA
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$	^I Sink	2.0	'2		
Source ($V_{E/A \text{ out}} = 5.0 \text{ V}$, $V_{FB} = 2.3 \text{ V}$)	ISource	-2.0	-	-0.2	
$T_A = -25^\circ \text{ to } +85^\circ \text{C}$					
Output Voltage Swing	V		0.5	7.5	V
High State ($I_{E/A \text{ out (source)}} = 0.5 \text{ mA}$, $V_{FB} = 2.3 \text{ V}$) Low State ($I_{E/A \text{ out (sink)}} = 0.33 \text{ mA}$, $V_{FB} = 2.7 \text{ V}$)	V _{OH} V _{OL}	5.5 _	6.5 1.0	7.5 1.1	
REFERENCE SECTION	VOL		1.0	1	
Reference Output Voltage (V _{CC} = 10 to 15 V)	V _{ref}	2.4	2.5	2.6	V
Reference Current Range ($I_{ref} = V_{ref}/R_{ref}$, R = 5.0 k to 25 k Ω)	l _{ref}	-500	_	-100	μΑ
Reference Voltage Over I _{ref} Range	ΔV _{ref}	-40	_	40	mV
OSCILLATOR AND SYNCHRONIZATION SECTION	△vrer	-40	_	40	1110
Frequency	fooo				kHz
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	fosc	44.5	48	51.5	KI IZ
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$		44	-	52	
Frequency Change with Voltage (V _{CC} = 10 to 15 V)	Δfosc/ΔV	-	0.05	-	%/V
Frequency Change with Temperature (T _A = -25° to +85°C)	Δf _{OSC} /ΔT	-	0.05	-	%/°C
Oscillator Voltage Swing (Peak-to-Peak)	V _{OSC(pp)}	1.65	1.8	1.95	V
Ratio Charge Current/Reference Current	I _{charge} /I _{ref}				_
$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C } (V_{CT} = 2.0 \text{ V})$		0.375	0.4	0.425	
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$		0.37	-	0.43	
Fixed Maximum Duty Cycle = Idischarge/(Idischarge + Icharge)	D	78	80	82	%
Ratio Standby Discharge Current versus I _{R F Stby} (Note 6)	Idisch-Stby/				_
$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$ $T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C (Note 8)}$	IR F Stby	0.46 0.43	0.53	0.6 0.63	
	\/p = o::	2.4	2.5	2.6	V
VR F Stby (IR F Stby = 100 μA)	VR F Stby	18	2.3	2.0	kHz
Frequency in Standby Mode (R _{F Stby} (Pin 15) = 25 kΩ) Current Range	F _{Stby}	-200	_	-50	
· ·	IR F Stby				μΑ
Synchronization Input Threshold Voltage (Note 7)	VinthH VinthL	3.2 0.45	3.7 0.7	4.3 0.9	V
Synchronization Input Current	I _{Sync-in}	-5.0	_	0	μА
Minimum Synchronization Pulse Width (Note 8)	tSync	_	-	0.5	μs
UNDERVOLTAGE LOCKOUT SECTION	, ,			·	
Startup Threshold	V _{stup-th}	13.6	14.5	15.4	V
Output Disable Voltage After Threshold Turn-On (UVLO 1)	V _{disable1}				V
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		8.6	9.0	9.4	
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$		8.3	-	9.6	
Reference Disable Voltage After Threshold Turn-On (UVLO 2)	V _{disable2}	7.0	7.5	8.0	V

- NOTES: 3. Adjust V_{CC} above the startup threshold before setting to 12 V.
 4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
 6. Standby is disabled for V_R P Stby < 25 mV typical.
 7. If not used, Synchronization input must be connected to Ground.
 8. Synchronization Pulse Width must be shorter than t_{OSC} = 1/f_{OSC}.

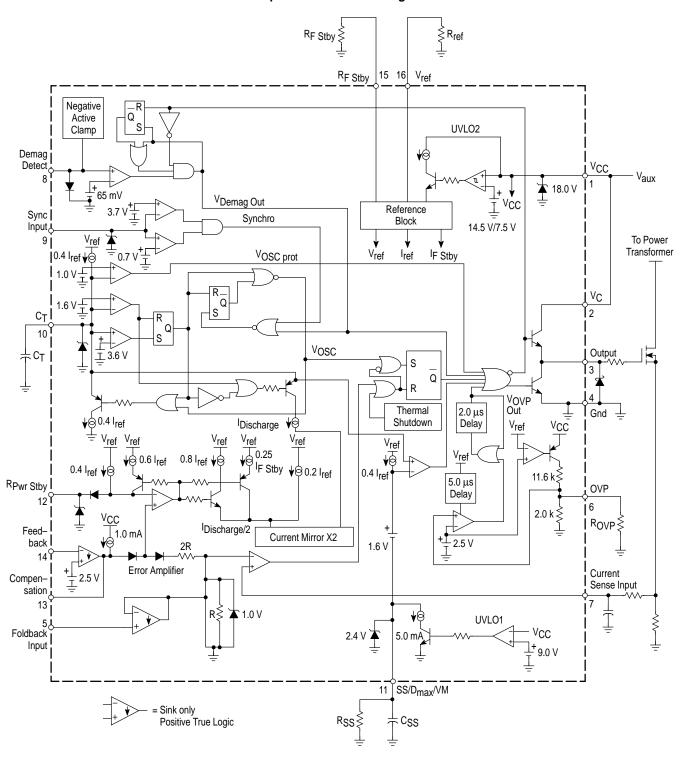
ELECTRICAL CHARACTERISTICS (continued) (V_{CC} and V_{C} = 12 V, [Note 3], R_{ref} = 10 k Ω , C_{T} = 820 pF, for typical values T_{A} = 25°C, for min/max values T_{A} = -25° to +85°C [Note 4], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DEMAGNETIZATION DETECTION SECTION (Note 9)					_
Demagnetization Detect Input					
Demagnetization Comparator Threshold (VPin 9 Decreasing)	V _{demag-th}	50	65	80	mV
Propagation Delay (Input to Output, Low to High)		-	0.25	-	μs
Input Bias Current (V _{demag} = 65 mV)	I _{demag} lb	-0.5	-	_	μΑ
Negative Clamp Level (I _{demag} = -2.0 mA)	C _{L(neg)}	_	-0.38	_	V
Positive Clamp Level (I _{demag} = 2.0 mA)	C _{L(pos)}	-	0.72	_	V
SOFT-START SECTION (Note 11)					
Ratio Charge Current/I _{ref}	I _{ss(ch)} /I _{ref}				_
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	\ \ \ \ \	0.37	0.4	0.43	
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$		0.36	-	0.44	
Discharge Current (V _{Soft-Start} = 1.0 V)	l _{discharge}	1.5	5.0	_	mA
Clamp Level	V _{SS(CL)}	2.2	2.4	2.6	V
Duty Cycle (R _{Soft-Start} = 12 kΩ)	D _{soft-start 12k}	36	42	49	%
(Vsoft-start (Pin 11) = 0.1 V)	D _{soft-start}	_	_	0	
OVERVOLTAGE SECTION			•		•
Protection Threshold Level on VOVP	V _{OVP-th}	2.42	2.5	2.58	V
Propagation Delay (V _{OVP} > 2.58 V to V _{out} Low)	071	1.0	_	3.0	μs
Protection Level on V _{CC}	VCC prot				V
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	VCC prot	16.1	17	17.9	ľ
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$		15.9	_	18.1	
Input Resistance	_				kΩ
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$		1.5	2.0	3.0	
$T_A = -25^\circ \text{ to } +85^\circ \text{C}$		1.4	_	3.4	
FOLDBACK SECTION (Note 10)					
Current Sense Voltage Threshold (Vfoldback (Pin 5) = 0.9 V)	V _{CS-th}	0.86	0.89	0.9	V
Foldback Input Bias Current (Vfoldback (Pin 5) = 0 V)	Ifoldback-lb	-6.0	-2.0	_	μΑ
STANDBY SECTION	'			I.	
Ratio I _{R P Stbv} /I _{ref}	I _{R P Stby} /I _{ref}				_
$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	IN Olby ICI	0.37	0.4	0.43	
$T_A = -25^\circ \text{ to } +85^\circ \text{C}$		0.36	-	0.44	
Ratio Hysteresis (V _h Required to Return to Normal Operation from Standby	V _h /V _R P Stby				_
Operation)	1				
$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		1.42	1.5	1.58	
$T_A = -25^{\circ} \text{ to } +85^{\circ}\text{C}$.	1.4	-	1.6	
Current Sense Voltage Threshold (V _{R P Stby} (Pin 12) = 1.0 V)	V _{CS} -Stby	0.28	0.31	0.34	V
CURRENT SENSE SECTION					
Maximum Current Sense Input Threshold	VCS-th	0.96	1.0	1.04	V
(Vfeedback (Pin 14) = 2.3 V and Vfoldback (Pin 6) = 1.2 V)					
Input Bias Current	I _{CS-ib}	-10	-2.0	_	μΑ
Propagation Delay (Current Sense Input to Output at V_{TH} of MOS transistor = 3.0 V)	_	_	120	200	ns
TOTAL DEVICE				<u> </u>	
Power Supply Current	Icc				mA
Startup (V _{CC} = 13 V with V _{CC} Increasing)		-	0.3	0.45	
Operating $T_A = -25^{\circ}$ to +85°C (Note 3)		13	17	20	
Power Supply Zener Voltage (I _{CC} = 25 mA)	VZ	18.5			V
Thermal Shutdown	_	_	155	_	°C

- NOTES: 3. Adjust V_{CC} above the startup threshold before setting to 12 V.
 4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
 9. This function can be inhibited by connecting Pin 8 to Gnd. This allows a continuous current mode operation.

10. This function can be inhibited by connecting Pin 5 to V_{CC}.
11. The MC44603A can be shut down by connecting the Soft–Start pin (Pin 11) to Ground.

Representative Block Diagram



This device contains 243 active transistors.

1.0 M

Oscillator Frequency

100

CT = 100 pF

CT = 500 pF

CT = 1000 pF

CT = 1000 pF

100 k

fOSC, Oscillator Frequency (Hz)

 $C_T = 2200 pF$

3.0

10 k

Figure 1. Timing Resistor versus

Figure 2. Standby Mode Timing Capacitor versus Oscillator Frequency

10000

RF Stby = 2.0 k

RF Stby = 2.0 k

RF Stby = 27 k

RF Stby = 100 k

100 k

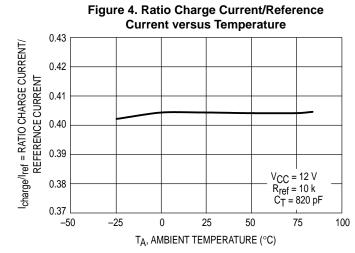
100 k

100 k

1.0 M

fOSC, Oscillator Frequency (Hz)

Figure 3. Oscillator Frequency versus Temperature 52 fOSC, OSCILLATOR FREQUENCY (KHz) 51 50 49 48 47 46 V_{CC} = 12 V R_{ref} = 10 k C_T = 820 pF 45 -25 0 25 50 75 100 -50 TA, AMBIENT TEMPERATURE (°C)



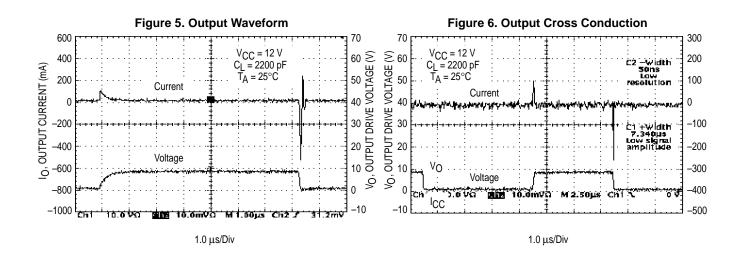
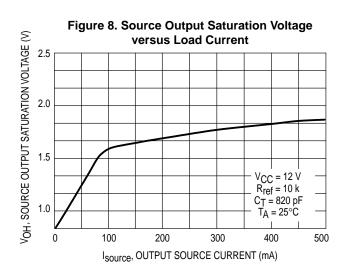
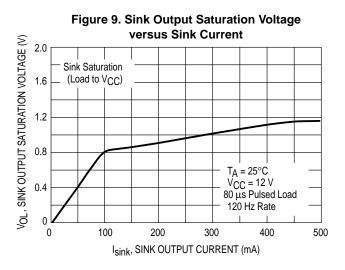
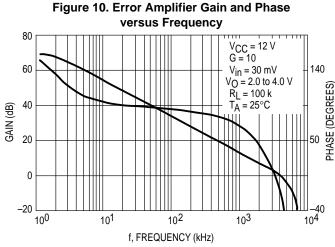
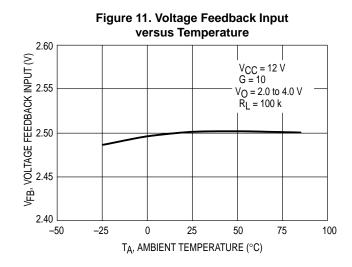


Figure 7. Oscillator Discharge Current versus Temperature 500 disch, DISCHARGE CURRENT (µA) 475 450 425 400 375 V_{CC} = 12 V 350 $R_{ref} = 10 k$ CT = 820 pF 325 300 75 -50 -25 100 TA, AMBIENT TEMPERATURE (°C)









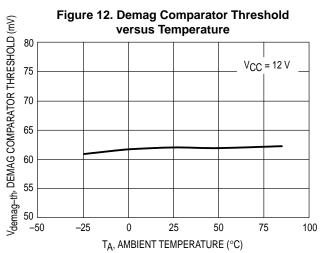


Figure 13. Current Sense Gain versus Temperature 3.2 A VCS, CURRENT SENSE GAIN 3.1 3.0 V_{CC} = 12 V R_{ref} = 10 k 2.9 $\dot{C}_{T} = 820 \text{ pF}$ 2.8 75 100 -50 -25 50 TA, AMBIENT TEMPERATURE (°C)

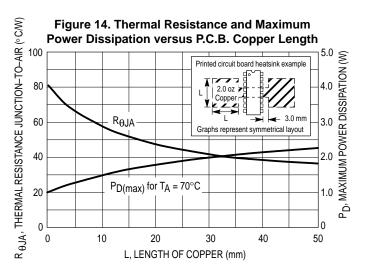


Figure 15. Propagation Delay Current Sense Input to Output versus Temperature

140

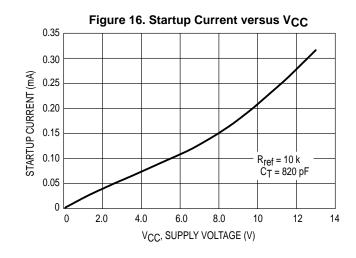
120

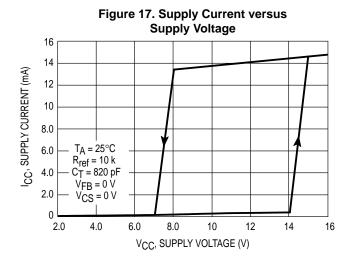
VCC = 12 V

Rref = 10 k

CT = 820 pF

TA, AMBIENT TEMPERATURE (°C)





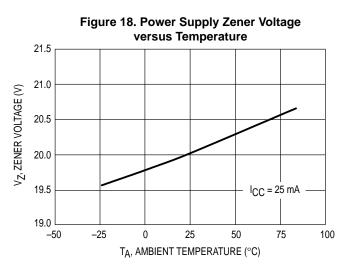


Figure 19. Startup Threshold Voltage versus Temperature

15.5

15.5

14.5

14.5

14.5

14.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.5

15.

Figure 20. Disable Voltage After Threshold Turn-On (UVLO1) versus Temperature 9.50 9.25 Vdisable1, UVLO1 (V) 9.00 V_{CC} Decreasing 8.55 8.50 -25 75 -50 25 50 100 TA, AMBIENT TEMPERATURE (°C)

Figure 21. Disable Voltage After Threshold Turn–On (UVLO2) versus Temperature

8.0

7.8

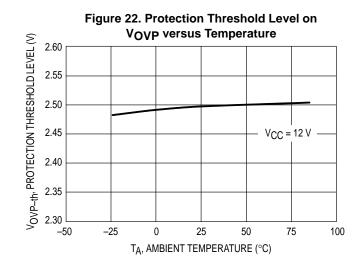
7.6

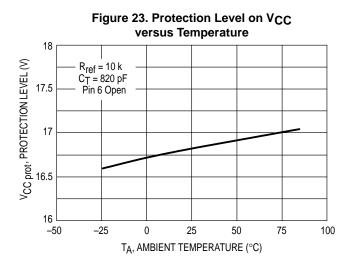
7.4

VCC Decreasing

7.0

1. AMBIENT TEMPERATURE (°C)





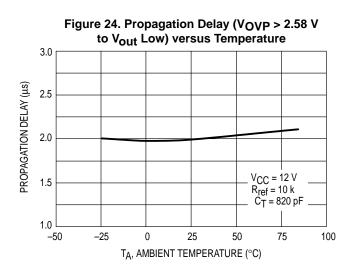


Figure 25. Standby Reference Current versus Temperature IR P Stby, STANDBY REFERENCE CURRENT (µA) 270 265 260 255 250 VR P Stdby (Pin 12) Voltage Increasing 245 240 235 230 -50 -25 50 75 100

TA, AMBIENT TEMPERATURE (°C)

Figure 26. Current Sense Voltage Threshold **Standby Mode versus Temperature** 0.33 VCS-stby , CURRENT SENSE THRESHOLD STANDBY MODE (V) 0.32 V_{CC} = 12 V R_{ref} = 10 k C_T = 820 pF Pin 12 Clamped 0.31 at 1.0 V 0.30 -50 -25 25 50 75 100 TA, AMBIENT TEMPERATURE (°C)

PIN FUNCTION DESCRIPTION

Pin	Name	Description			
1	Vcc	This pin is the positive supply of the IC. The operating voltage range after startup is 9.0 to 14.5 V.			
2	VC	The output high state (V _{OH}) is set by the voltage applied to this pin. With a separate connection to the power source, it can reduce the effects of switching noise on the control circuitry.			
3	Output	eak currents up to 750 mA can be sourced or sunk, suitable for driving either MOSFET or Bipolar ansistors. This output pin must be shunted by a Schottky diode, 1N5819 or equivalent.			
4	Gnd	The ground pin is a single return, typically connected back to the power source; it is used as control and power ground.			
5	Foldback Input	The foldback function provides overload protection. Feeding the foldback input with a portion of the V _{CC} voltage (1.0 V max) establishes on the system control loop a foldback characteristic allowing a smoother startup and sharper overload protection. Above 1.0 V the foldback input is inactive.			
6	Overvoltage Protection	When the overvoltage protection pin receives a voltage greater than 17 V, the device is disabled and requires a complete restart sequence. The overvoltage level is programmable.			
7	Current Sense Input	A voltage proportional to the current flowing into the power switch is connected to this input. The PWM latch uses this information to terminate the conduction of the output buffer when working in a current mode of operation. A maximum level of 1.0 V allows either current or voltage mode operation.			
8	Demagnetization Detection	A voltage delivered by an auxiliary transformer winding provides to the demagnetization pin an indication of the magnetization state of the flyback transformer. A zero voltage detection corresponds to complete core saturation. The demagnetization detection ensures a discontinuous mode of operation. This function can be inhibited by connecting Pin 8 to Gnd.			
9	Synchronization Input	The synchronization input pin can be activated with either a negative pulse going from a level between 0.7 V and 3.7 V to Gnd or a positive pulse going from a level between 0.7 V and 3.7 V up to a level higher than 3.7 V. The oscillator runs free when Pin 9 is connected to Gnd.			
10	СТ	The normal mode oscillator frequency is programmed by the capacitor C _T choice together with the R _{ref} resistance value. C _T , connected between Pin 10 and Gnd, generates the oscillator sawtooth.			
11	Soft-Start/D _{max} / Voltage-Mode	A capacitor, resistor or a voltage source connected to this pin limits the switching duty–cycle. This pin can be used as a voltage mode control input. By connecting Pin 11 to Ground, the MC44603A can be shut down.			
12	RP Standby	A voltage level applied to the Rp Standby pin determines the output power level at which the oscillator will turn into the reduced frequency mode of operation (i.e. standby mode). An internal hysteresis comparator allows to return in the normal mode at a higher output power level.			
13	E/A Out	The error amplifier output is made available for loop compensation.			
14	Voltage Feedback	This is the inverting input of the Error Amplifier. It can be connected to the switching power supply output through an optical (or other) feedback loop.			
15	RF Standby	The reduced frequency or standby frequency programming is made by the RF Standby resistance choice.			
16	R _{ref}	R_{ref} sets the internal reference current. The internal reference current ranges from 100 μA to 500 μA. This requires that 5.0 k Ω ≤ R_{ref} ≤ 25 k Ω .			

Figure 27. Starting Behavior and Overvoltage Management

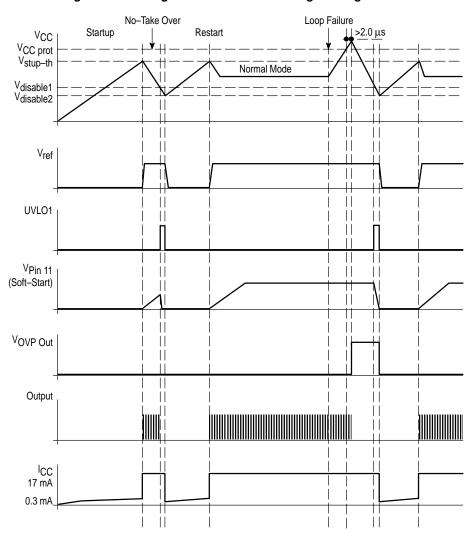


Figure 28. Demagnetization

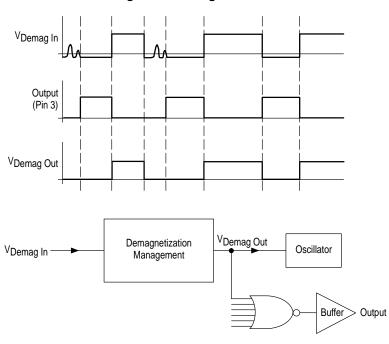


Figure 29. Switching Off Behavior

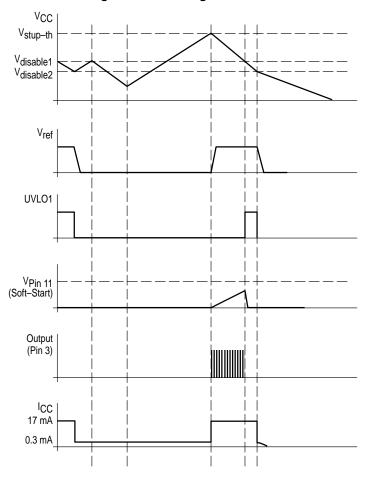


Figure 30. Oscillator

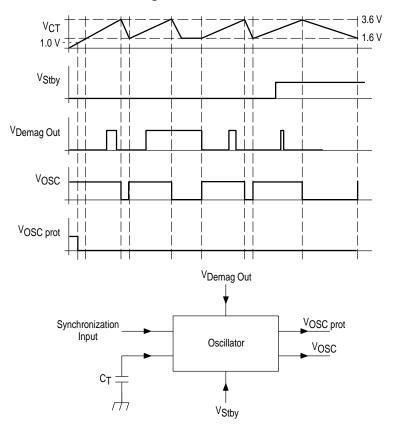
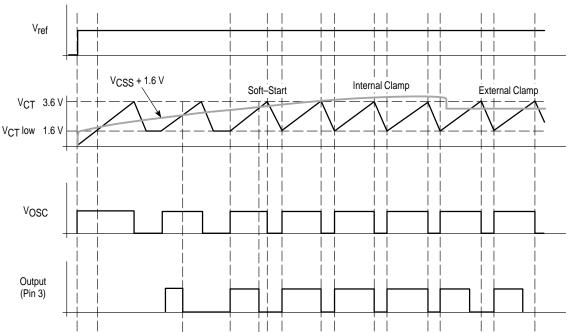


Figure 31. Soft-Start & Dmax



OPERATING DESCRIPTION

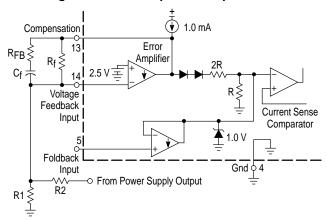
Error Amplifier

A fully compensated Error Amplifier with access to the inverting input and output is provided. It features a typical dc voltage gain of 70 dB. The noninverting input is internally biased at 2.5 V and is not pinned out. The converter output voltage is typically divided down and monitored by the inverting input. The maximum input bias current with the inverting input at 2.5 V is –2.0 μA . This can cause an output voltage error that is equal to the product of the input bias current and the equivalent input divider source resistance.

The Error Amp output (Pin 13) is provided for external loop compensation. The output voltage is offset by two diode drops (\approx 1.4 V) and divided by three before it connects to the inverting input of the Current Sense Comparator. This guarantees that no drive pulses appear at the Output (Pin 3) when Pin 13 is at its lowest state (Vol). The Error Amp minimum feedback resistance is limited by the amplifier's minimum source current (0.2 mA) and the required output voltage (Voh) to reach the current sense comparator's 1.0 V clamp level:

$$R_{f(min)} \approx \frac{3.0 (1.0 V) + 1.4 V}{0.2 mA} = 22 k\Omega$$

Figure 32. Error Amplifier Compensation



Current Sense Comparator and PWM Latch

The MC44603A can operate as a current mode controller or as a voltage mode controller. In current mode operation, the MC44603A uses the current sense comparator. The output switch conduction is initiated by the oscillator and terminated when the peak inductor current reaches the

threshold level established by the Error Amplifier output (Pin 13). Thus, the error signal controls the peak inductor current on a cycle-by-cycle basis. The Current Sense Comparator PWM Latch ensures that only a single pulse appears at the Source Output during the appropriate oscillator cycle.

The inductor current is converted to a voltage by inserting the ground referenced sense resistor R_S in series with the power switch Q1.

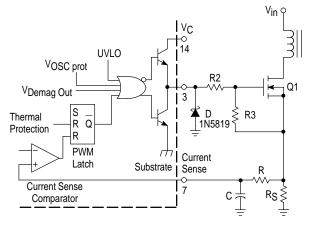
This voltage is monitored by the Current Sense Input (Pin 7) and compared to a level derived from the Error Amp output. The peak inductor current under normal operating conditions is controlled by the voltage at Pin 13 where:

$$I_{pk} \approx \frac{V(Pin \ 13) - 1.4 \ V}{3 \ R_{S}}$$

The Current Sense Comparator threshold is internally clamped to 1.0 V. Therefore, the maximum peak switch current is:

$$I_{pk(max)} \approx \frac{1.0 \text{ V}}{R_S}$$

Figure 33. Output Totem Pole



Series gate resistor, R2, will dampen any high frequency oscillations caused by the MOSFET input capacitance and any series wiring inductance in the gate–source circuit. Diode D is required if the negative current into the output drive pin exceeds 15 mA.

Oscillator

The oscillator is a very accurate sawtooth generator that can work either in free mode or in synchronization mode. In this second mode, the oscillator stops in the low state and waits for a demagnetization or a synchronization pulse to start a new charging cycle.

• The Sawtooth Generation:

In the steady state, the oscillator voltage varies between about 1.6 V and 3.6 V.

The sawtooth is obtained by charging and discharging an external capacitor C_T (Pin 10), using two distinct current sources = I_{charge} and $I_{discharge}$. In fact, C_T is permanently connected to the charging current source (0.4 I_{ref}) and so, the discharge current source has to be higher than the charge current to be able to decrease the C_T voltage (refer to Figure 35).

This condition is performed, its value being (2.0 I_{ref}) in normal working and (0.4 I_{ref} + 0.5 I_F Stby in standby mode).

Figure 34. Oscillator

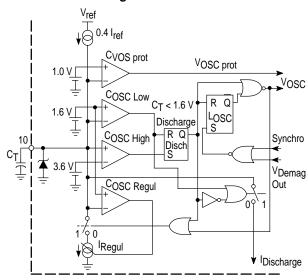
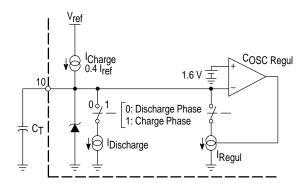


Figure 35. Simplified Block Oscillator



Two comparators are used to generate the sawtooth. They compare the C_T voltage to the oscillator valley (1.6 V) and peak reference (3.6 V) values. A latch (L_{disch}) memorizes the oscillator state.

In addition to the charge and discharge cycles, a third state can exist. This phase can be produced when, at the end of the discharge phase, the oscillator has to wait for a synchronization or demagnetization pulse before restarting. During this delay, the CT voltage must remain equal to the oscillator valley value (\approx 1.6 V). So, a third regulated current source IRegul controlled by COSC Regul, is connected to CT in order to perfectly compensate the (0.4 Iref) current source that permanently supplies CT.

The maximum duty cycle is 80%. Indeed, the on–time is allowed only during the oscillator capacitor charge.

Consequently:

 $T_{charge} = C_T \times \Delta V/I_{charge}$ $T_{discharge} = C_T \times \Delta V/I_{discharge}$

where:

T_{charge} is the oscillator charge time ΔV is the oscillator peak–to–peak value I_{charge} is the oscillator charge current

T_{discharge} is the oscillator discharge time l_{discharge} is the oscillator discharge current

So, as $fS = 1 / (T_{charge} + T_{discharge})$ when the Regul arrangement is not activated, the operating frequency can be obtained from the graph in Figure 1.

NOTE: The output is disabled by the signal V_{OSC prot} when V_{CT} is lower than 1.0 V (refer to Figure 30).

Synchronization and Demagnetization Blocks

To enable the output, the LOSC latch complementary output must be low. Reset is activated by the L_{disch} output during the discharge phase. To restart, the L_{OSC} has to be set (refer to Figure 34). To perform this, the demagnetization signal and the synchronization must be low.

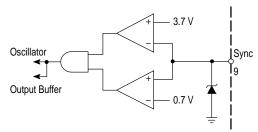
· Synchronization:

The synchronization block consists of two comparators that compare the synchronization signal (external) to 0.7 and 3.7 V (typical values). The comparators' outputs are connected to the input of an AND gate so that the final output of the block should be :

- high when 0.7 < SYNC < 3.7 V
- low in the other cases.

As a low level is necessary to enable the output, synchronized low level pulses have to be generated on the output of the synchronization block. If synchronization is not required, the Pin 9 must be connected to the ground.

Figure 36. Synchronization



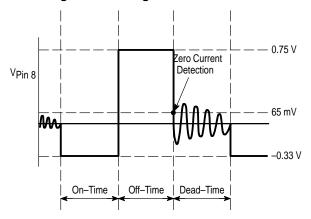
• Demagnetization:

In flyback applications, a good means to detect magnetic saturation of the transformer core, or demagnetization, consists in using the auxiliary winding voltage. This voltage is:

- negative during the on-time,
- positive during the off–time,
- equal to zero for the dead–time with generally some ringing (refer to Figure 37).

That is why, the MC44603A demagnetization detection consists of a comparator that can compare the auxiliary winding voltage to a reference that is typically equal to 65 mV.

Figure 37. Demagnetization Detection



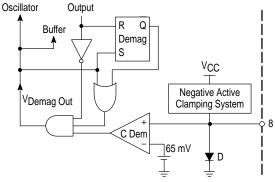
A diode D has been incorporated to clamp the positive applied voltages while an active clamping system limits the negative voltages to typically –0.33 V. This negative clamp level is sufficient to avoid the substrate diode switching on.

In addition to the comparator, a latch system has been incorporated in order to keep the demagnetization block output level low as soon as a voltage lower than 65 mV is detected and as long as a new restart is produced (high level on the output) (refer to Figure 38). This process prevents ringing on the signal at Pin 8 from disrupting the demagnetization detection. This results in a very accurate demagnetization detection.

The demagnetization block output is also directly connected to the output, disabling it during the demagnetization phase (refer to Figure 33).

NOTE: The demagnetization detection can be inhibited by connecting Pin 8 to the ground.

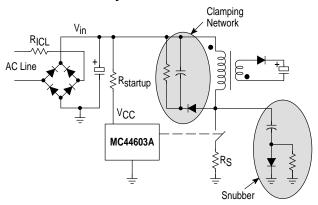
Figure 38. Demagnetization Block



Standby

• Power Losses in a Classical Flyback Structure

Figure 39. Power Losses in a Classical Flyback Structure



In a classical flyback (as depicted in Figure 39), the standby losses mainly consist of the energy waste due to:

- the startup resistor $R_{startup}$ \rightarrow $P_{startup}$
- the consumption of the IC and the power switch control $$\to$ P_{control}$
- the inrush current limitation resistor $R_{\mbox{\scriptsize ICL}} \rightarrow P_{\mbox{\scriptsize ICL}}$
- the switching losses in the power switch \rightarrow PSW the snubber and clamping network \rightarrow PSN-CLN

P_{startup} is nearly constant and is equal to:

P_{ICL} only depends on the current drawn from the mains. Losses can be considered constant. This waste of energy decreases when the standby losses are reduced.

P_{control} increases when the oscillator frequency is increased (each switching requires some energy to turn on the power switch).

PSW and PSN-CLN are proportional to the switching frequency.

Consequently, standby losses can be minimized by decreasing the switching frequency as much as possible.

The MC44603A was designed to operate at a standby frequency lower than the normal working one.

• Standby Power Calculations with MC44603A

During a switching period, the energy drawn by the transformer during the on–time to be transferred to the output during the off–time, is equal to:

$$E = \frac{1}{2} \times L \times I_{pk}^2$$

where:

- L is the transformer primary inductor,
- Ipk is the inductor peak current.

Input power is labelled Pin:

$$P_{in} = 0.5 \times L \times I_{pk}^2 \times f_S$$

where fs is the normal working switching frequency.

Also,

$$I_{pk} = \frac{VCS}{R_S}$$

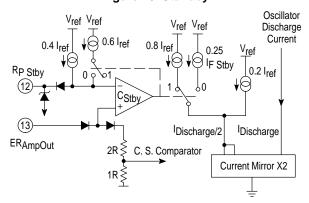
where Rs is the resistor used to measure the power switch current

Thus, the input power is proportional to V_{CS}² (V_{CS} being the internal current sense comparator input).

That is why the standby detection is performed by creating a VCS threshold. An internal current source (0.4 x I_{ref}) sets the threshold level by connecting a resistor to Pin 12.

As depicted in Figure 40, the standby comparator noninverting input voltage is typically equal to $(3.0 \times V_{CS} + V_{F})$ while the inverter input value is $(V_{R} + V_{F})$.

Figure 40. Standby



The V_{CS} threshold level is typically equal to $[(V_{R} P_{Stby})/3]$ and if the corresponding power threshold is labelled P_{thL} :

$$P_{thL} = 0.5 \times L \times \left(\frac{VR P Stby}{3.0 R_S}\right)^2 \times f_S$$

And as:

$$V_{R P Stby} = R_{P Stby} \times 0.4 \times I_{ref}$$

= $R_{R P Stby} \times 0.4 \times \frac{V_{ref}}{R_{ref}}$

$$RP Stby = \frac{10.6 \times RS \times R_{ref}}{V_{ref}} \times \sqrt{\frac{P_{thL}}{L \times fS}}$$

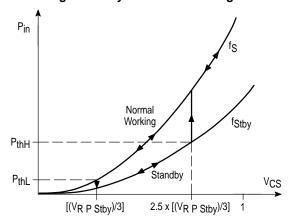
Thus, when the power drawn by the converter decreases, VCS decreases and when VCS becomes lower than [VCS–th x (VR P Stby)/3], the standby mode is activated. This results in an oscillator discharge current reduction in order to increase the oscillator period and to diminish the switching frequency. As it is represented in Figure 40, the (0.8 x Iref) current source is disconnected and is replaced by a lower value one (0.25 x IF Stby).

Where: IF Stby = Vref/RF Stby

In order to prevent undesired mode switching when power is close to the threshold value, a hysteresis that is proportional to VR P Stby is incorporated creating a second VCS threshold level that is equal to [2.5 x (VR P Stby)/3]. When the standby comparator output is high, a second current source (0.6 x Iref) is connected to Pin 12.

Finally, the standby mode function can be shown graphically in Figure 41.

Figure 41. Dynamic Mode Change



This curve shows that there are two power threshold levels:

- the low one:

- the high one:

$$P_{thH} = (2.5)^2 \times P_{thL} \times \frac{f_{Stby}}{f_{S}}$$

$$P_{thH} = 6.25 \times P_{thL} \times \frac{f_{Stby}}{f_{S}}$$

Maximum Duty Cycle and Soft-Start Control

Maximum duty cycle can be limited to values less than 80% by utilizing the D_{max} and soft–start control. As depicted in Figure 42, the Pin 11 voltage is compared to the oscillator sawtooth.

Figure 42. D_{max} and Soft-Start

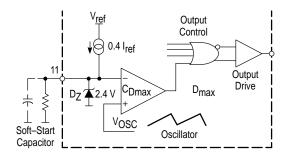
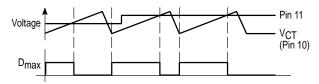


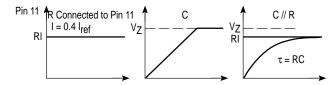
Figure 43. Maximum Duty Cycle Control



Using the internal current source (0.4 I_{ref}), the Pin 11 voltage can easily be set by connecting a resistor to this pin.

If a capacitor is connected to Pin 11, the voltage increases from 0 to its maximum value progressively (refer to Figure 44), thereby, implementing a soft–start. The soft–start capacitor is discharged internally when the V_{CC} (Pin 1) voltage drops below 9.0 V.

Figure 44. Different Possible Uses of Pin 11



If no external component is connected to Pin 11, an internal zener diode clamps the Pin 11 voltage to a value Vz that is higher than the oscillator peak value, disabling soft–start and maximum duty cycle limitation.

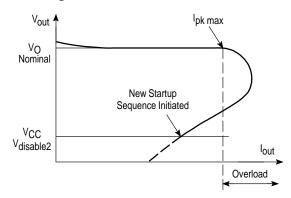
Foldback

As depicted in Figures 32 and 48, the foldback input (Pin 5) can be used to reduce the maximum V_{CS} value, providing foldback protection. The foldback arrangement is a programmable peak current limitation.

If the output load is increased, the required converter peak current becomes higher and V_{CS} increases until it reaches its maximum value (normally, V_{CS} max = 1.0 V).

Then, if the output load keeps on increasing, the system is unable to supply enough energy to maintain the output voltages in regulation. Consequently, the decreasing output can be applied to Pin 5, in order to limit the maximum peak current. In this way, the well known foldback characteristic can be obtained (refer to Figure 45).

Figure 45. Foldback Characteristic



NOTE: Foldback is disabled by connecting Pin 5 to VCC.

Overvoltage Protection

The overvoltage arrangement consists of a comparator that compares the Pin 6 voltage to V_{ref} (2.5 V) (refer to Figure 46).

If no external component is connected to Pin 6, the comparator noninverting input voltage is nearly equal to:

$$\left(\frac{2.0~k\Omega}{11.6~k\Omega+2.0~k\Omega}~\right)~x~V_{CC}$$

The comparator output is high when:

$$\left(\frac{2.0 \text{ k}\Omega}{11.6 \text{ k}\Omega + 2.0 \text{ k}\Omega}\right) \times V_{CC} \ge 2.5 \text{ V}$$

$$\Leftrightarrow V_{CC} \ge 17 \text{ V}$$

A delay latch (2.0 μs) is incorporated in order to sense overvoltages that last at least 2.0 μs .

If this condition is achieved, $V_{OVP\ Out}$, the delay latch output, becomes high. As this level is brought back to the input through an OR gate, $V_{OVP\ Out}$ remains high (disabling the IC output) until V_{ref} is disabled.

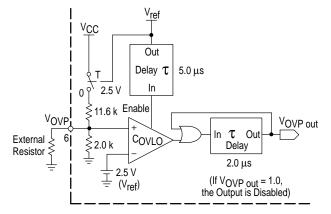
Consequently, when an overvoltage longer than 2.0 μs is detected, the output is disabled until VCC is removed and then re–applied.

The V_{CC} is connected after V_{ref} has reached steady state in order to limit the circuit startup consumption.

The overvoltage section is enabled 5.0 μs after the regulator has started to allow the reference $V_{\mbox{\scriptsize ref}}$ to stabilize.

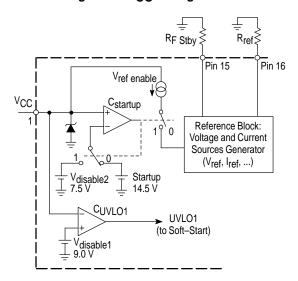
By connecting an external resistor to Pin 6, the threshold $V_{\hbox{\footnotesize{CC}}}$ level can be changed.

Figure 46. Overvoltage Protection



Undervoltage Lockout Section

Figure 47. VCC Management



As depicted in Figure 47, an undervoltage lockout has been incorporated to garantee that the IC is fully functional before allowing system operation.

This block particularly, produces V_{ref} (Pin 16 voltage) and I_{ref} that is determined by the resistor R_{ref} connected between Pin 16 and the ground:

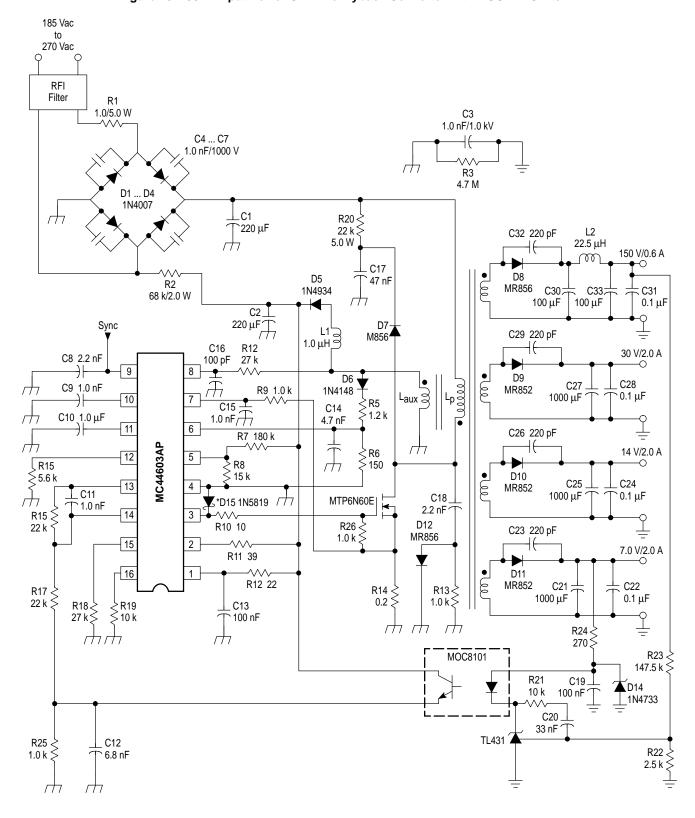
$$I_{ref} = \frac{V_{ref}}{R_{ref}}$$
 where $V_{ref} = 2.5 \text{ V (typically)}$

Another resistor is connected to the Reference Block: RF Stbv that is used to fix the standby frequency.

In addition to this, V_{CC} is compared to a second threshold level that is nearly equal to 9.0 V ($V_{disable1}$). UVLO1 is generated to reset the maximum duty cycle and soft–start block disabling the output stage as soon as V_{CC} becomes lower than $V_{disable1}$. In this way, the circuit is reset and made ready for the next startup, before the reference block is disabled (refer to Figure 29). Finally, the upper limit for the minimum normal operating voltage is 9.4 V (maximum value of $V_{disable1}$) and so the minimum hysteresis is 4.2 V. (($V_{stup-th}$) min = 13.6 V).

The large hysteresis and the low startup current of the MC44603A make it ideally suited for off-line converter applications where efficient bootstrap startup techniques are required.

Figure 48. 250 W Input Power Off-Line Flyback Converter with MOSFET Switch

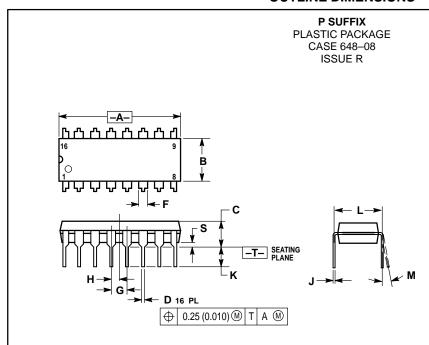


^{*} Diode D15 is required if the negative current into the output pin exceeds 15 mA.

250 W Input Power Fly-Back Converter 185 V - 270 V Mains Range MC44603AP & MTP6N60E

Tests	Conditions	Results
Line Regulation 150 V 30 V 14 V 7.0 V	V _{in} = 185 Vac to 270 Vac F _{mains} = 50 Hz I _{out} = 0.6 A I _{out} = 2.0 A I _{out} = 2.0 A I _{out} = 2.0 A	10 mV 10 mV 10 mV 20 mV
Load Regulation 150 V	V _{in} = 220 Vac I _{out} = 0.3 A to 0.6 A	50 mV
Cross Regulation	V _{in} = 220 Vac I _{out} (150 V) = 0.6 A I _{out} (30 V) = 0 A to 2.0 A I _{out} (14 V) = 2.0 A I _{out} (7.0 V) = 2.0 A	< 1.0 mV
Efficiency	V _{in} = 220 Vac, P _{in} = 250 W	81%
Standby Mode P input	V _{in} = 220 Vac, P _{out} = 0 W	3.3 W
Switching Frequency		20 kHz fully stable
Output Short Circuit	P _{out (max)} = 270 W	Safe on all outputs
Startup	P _{in} = 250 W	Vac = 160 V

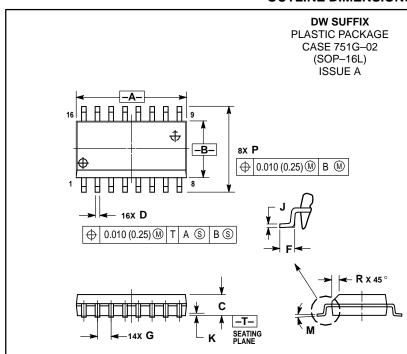
OUTLINE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27	BSC	
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	

OUTLINE DIMENSIONS



NOTES:

- NOTES:
 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER CIDE.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	10.15	10.45	0.400	0.411
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and manufacture of the application

Mfax is a trademark of Motorola, Inc.

How to reach us: USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 INTERNET: http://Design–NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 81–3–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



MC44603A/D